ANALOG DEVICES

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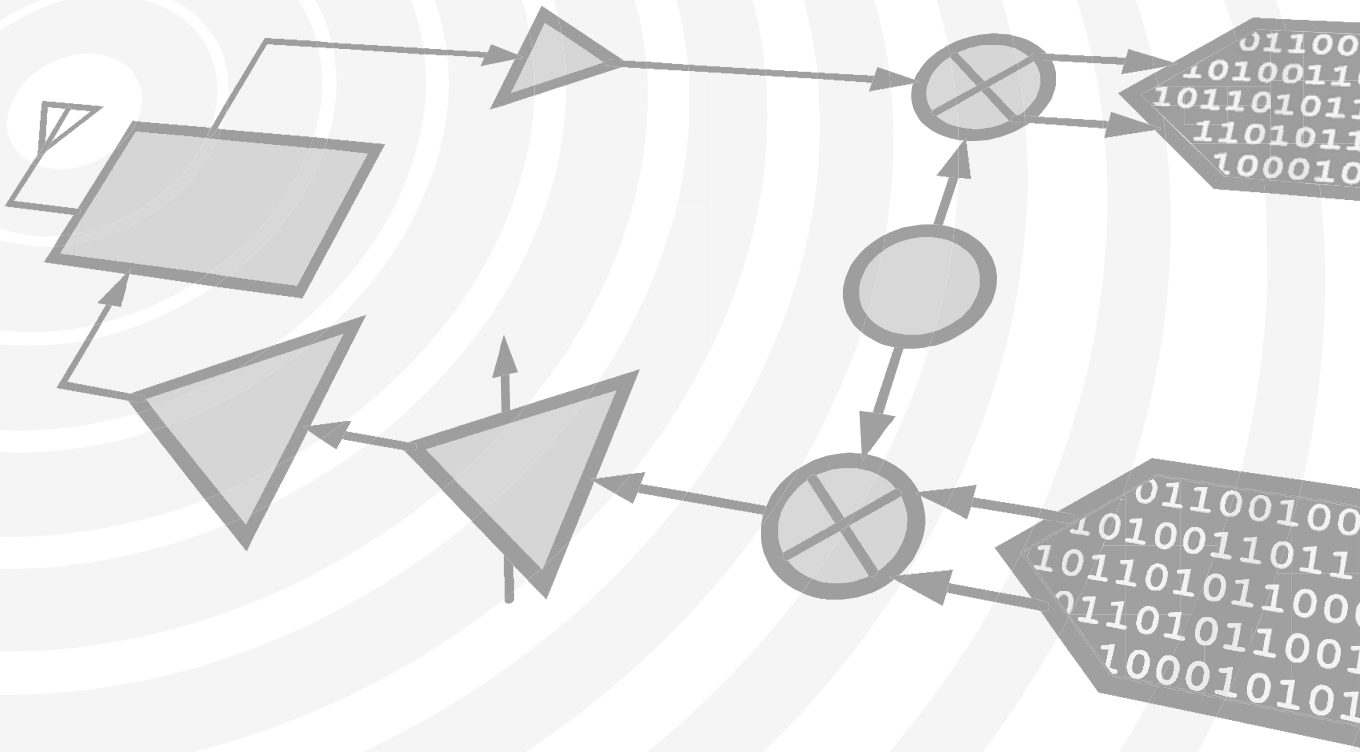
NO CONTENT ON THE ATTACHED DOCUMENT HAS CHANGED



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v01.0314

HMC6787ALC5A

GaAs MMIC I/Q UPCONVERTER 37 - 40 GHz

Typical Applications

The HMC6787ALC5A is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

Features

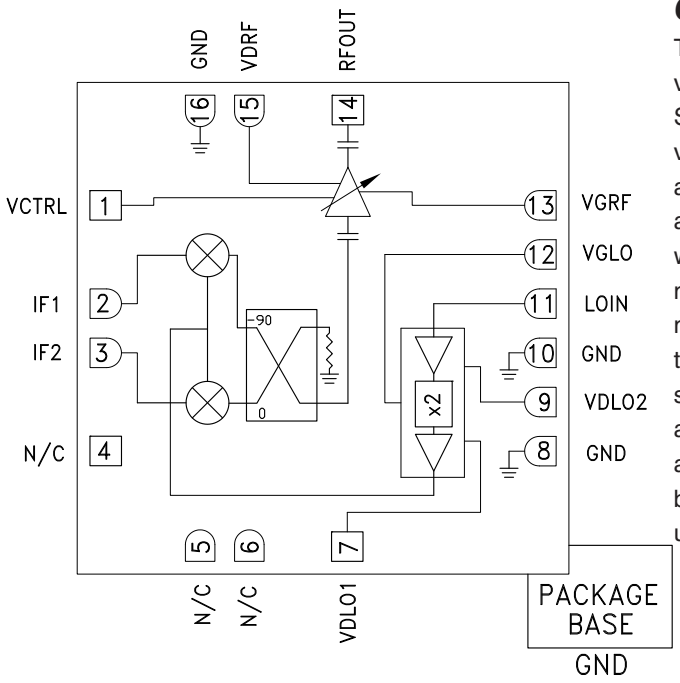
Conversion Gain: 10 dB

Sideband Rejection: 17 dBc

High Output IP3: +27 dBm

16 Lead 5x5 mm SMT Ceramic Package: 25 mm²

Functional Diagram



General Description

The HMC6787ALC5A is a compact GaAs MMIC I/Q variable gain upconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 11 dB with 17 dBc of sideband rejection, and 13 dB of gain control. The HMC6787ALC5A utilizes a RF variable gain amplifier preceded by an I/Q mixer where the LO is driven by a X2 multiplier. IF1 and IF2 mixer inputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC6787ALC5A is a much smaller alternative to hybrid style single sideband upconverter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

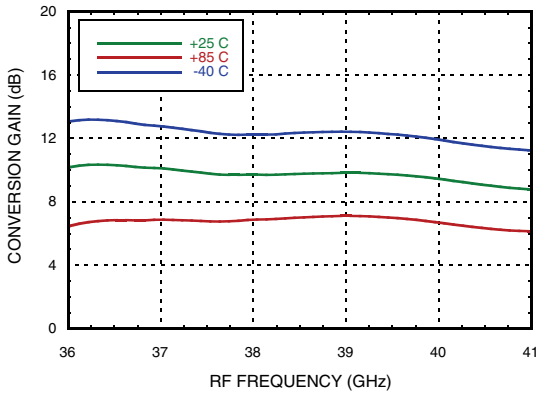
Electrical Specifications [1][2], T_A = +25°C, IF = 2350 MHz, LO = +4 dBm, VDLO1, 2 = +3V, IDLO = 150 mA, VDRF = +3V, IDRF = 200mA, USB [1][2]

Parameter	Min.	Typ.	Max.	Units
Frequency Range, RF		37 - 40		GHz
Frequency Range, LO		16.5 - 22		GHz
Frequency Range, IF		0 - 4		GHz
Conversion Gain	7	10		dB
Sideband Rejection		17		dBc
Dynamic Range		13		dB
1 dB Compression (Output)		14		dBm
IP3 (Output)		26		dBm
LO / RF Isolation		15		dB
Supply Current IDLO [2]		150		mA
Supply Current IDRF [2]		200		mA

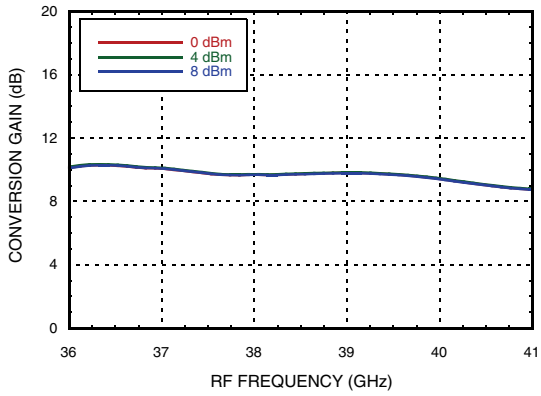
[1] Unless otherwise noted all measurements performed with low side LO, IF = 2350 MHz and external IF 90° hybrid.
[2] Adjust Vgg between -2 to 0V to achieve IDLO = 150 mA and IDRF = 200 mA Typical.

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2350 MHz

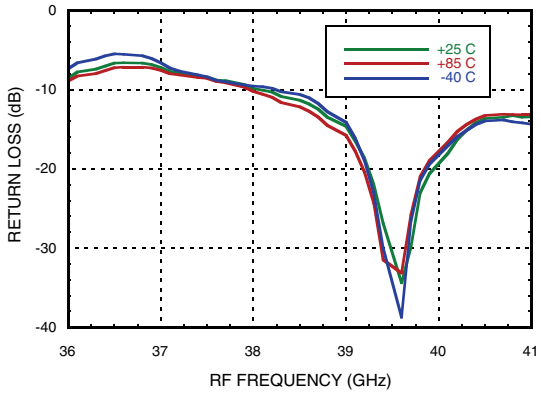
Conversion Gain, USB vs. Temperature



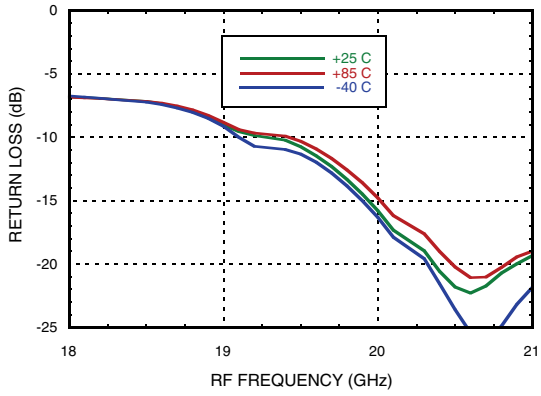
Conversion Gain, USB vs. LO Drive



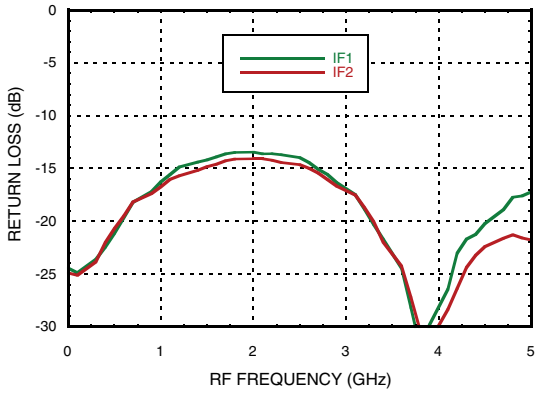
RF Return Loss vs. Temperature



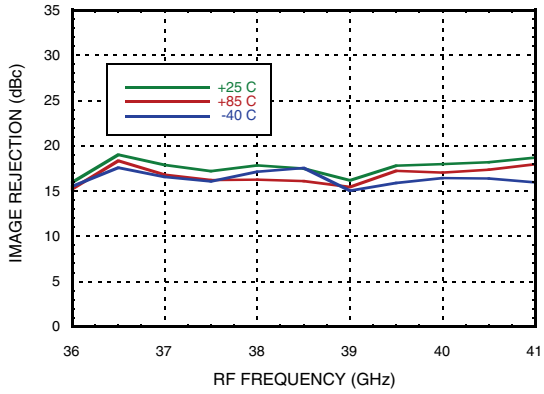
LO Return Loss vs. Temperature



IF Return Loss [1]



Sideband Rejection vs. Temperature



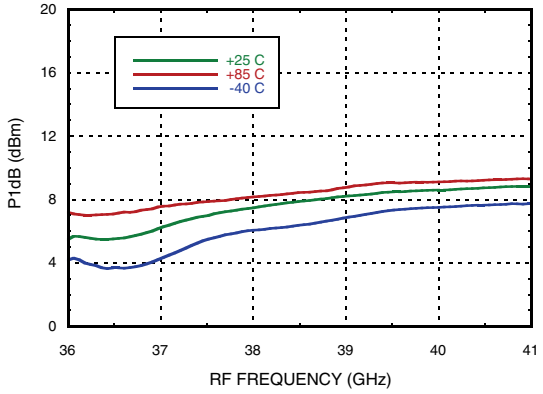
[1] Data taken without external IF 90° hybrid

HMC6787ALC5A

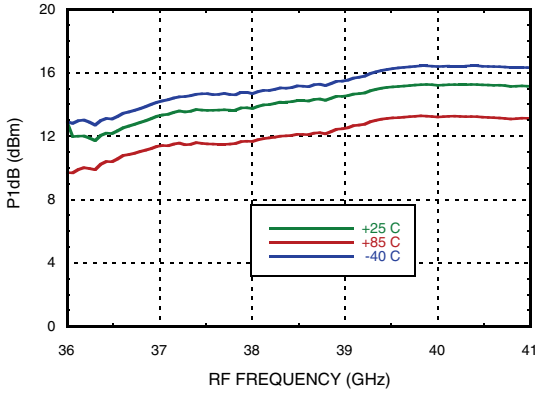
GaAs MMIC I/Q UPCONVERTER 37 - 40 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2350 MHz

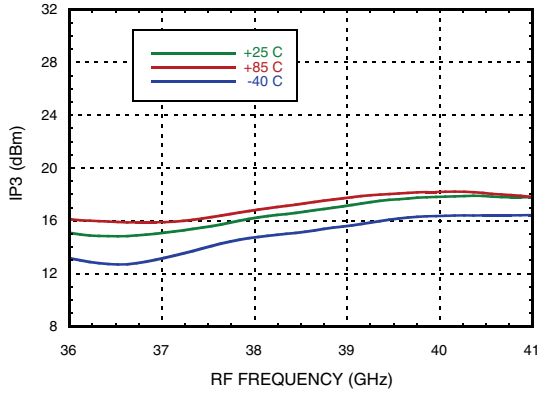
Input P1dB, USB vs. Temperature



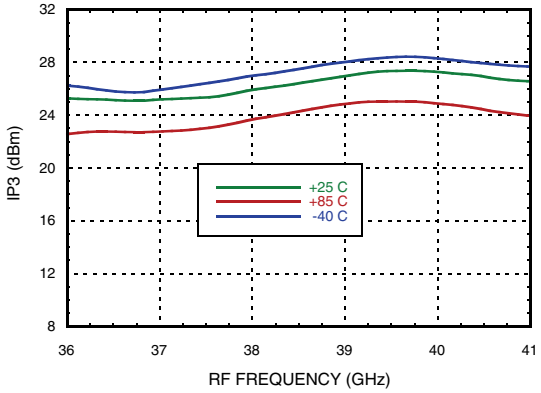
Output P1dB, USB vs. Temperature



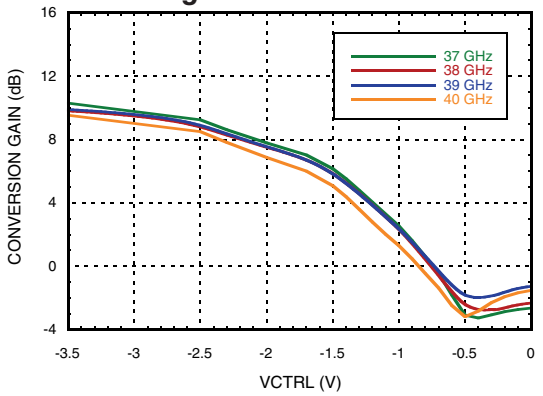
Input IP3, USB vs. Temperature



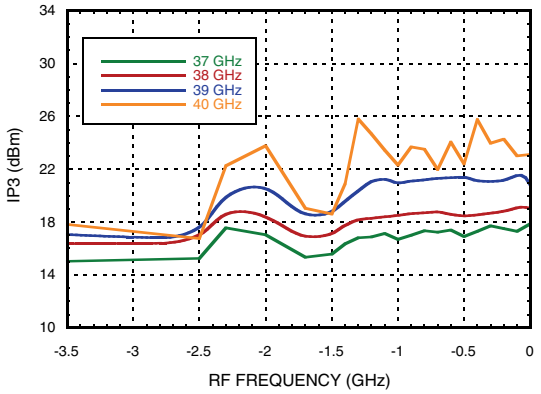
Output IP3, USB vs. Temperature



Conversion Gain, USB vs. Control Voltage

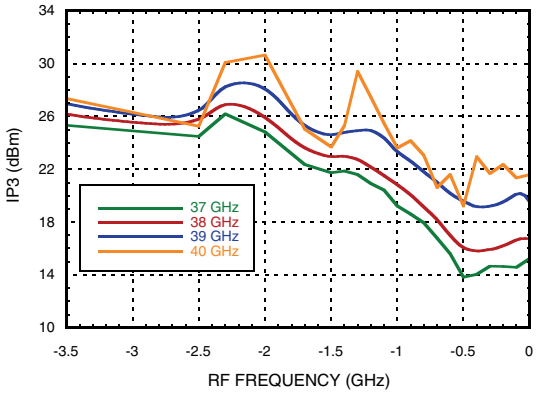


Input IP3, USB vs. Control Voltage

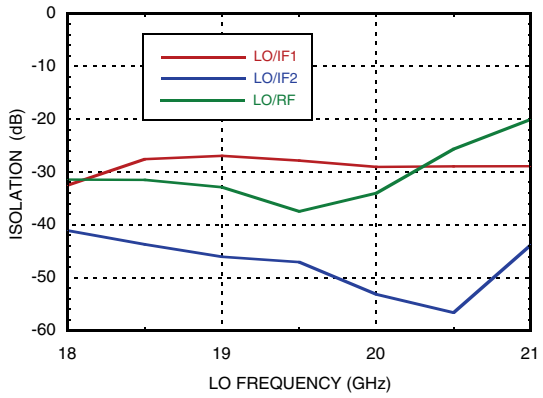


Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2350 MHz

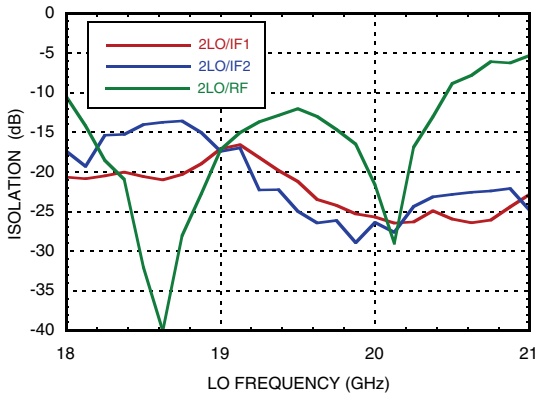
Output IP3, USB vs. Control Voltage



LO Isolation

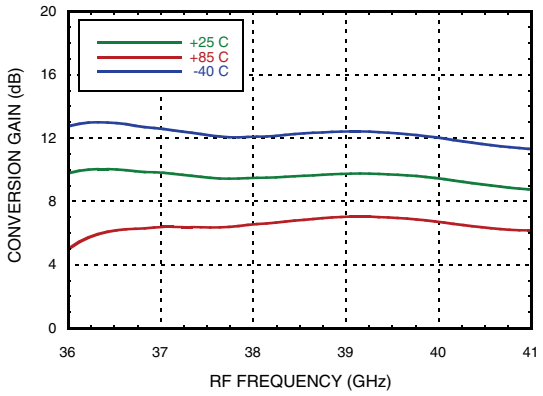


2LO Isolation

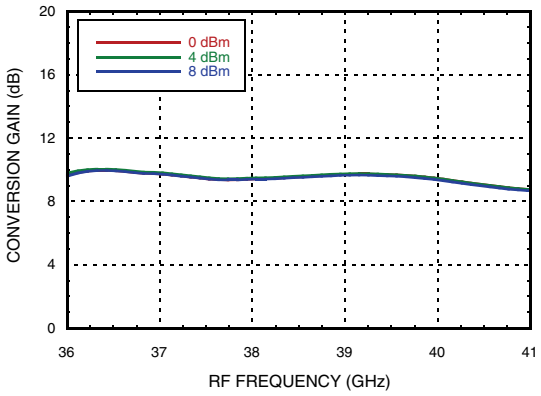


Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3000 MHz

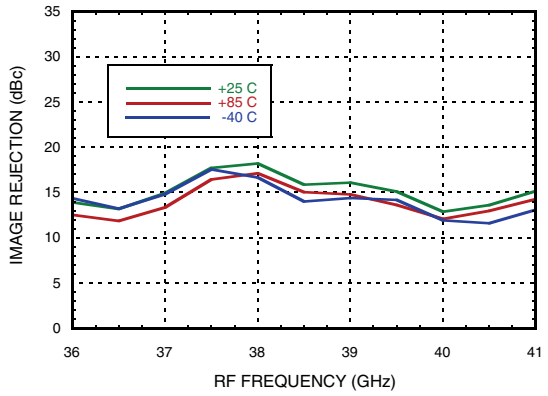
Conversion Gain, USB vs. Temperature



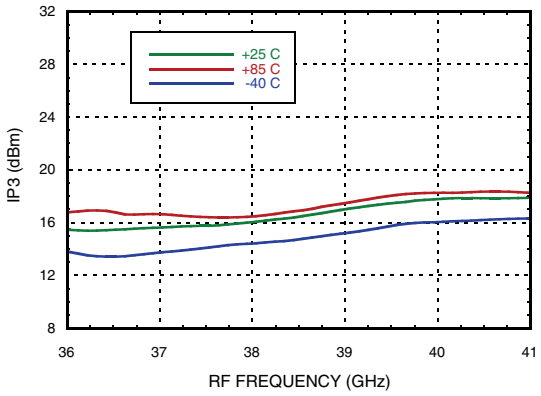
Conversion Gain, USB vs. LO Drive



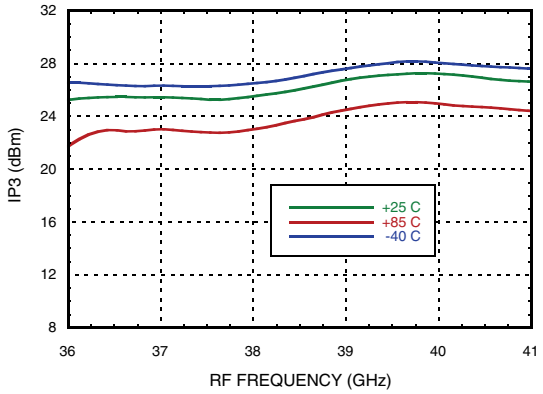
Sideband Rejection vs. Temperature



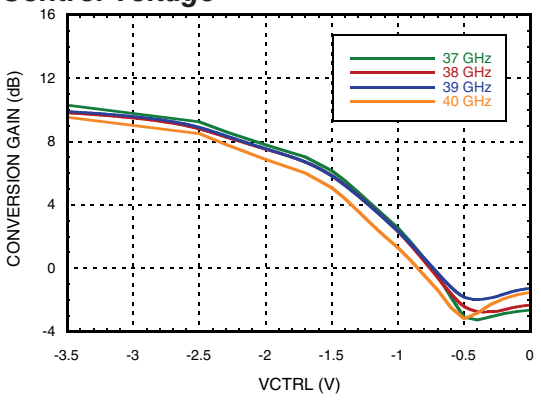
Input IP3, USB vs. Temperature



Output IP3, USB vs. Temperature

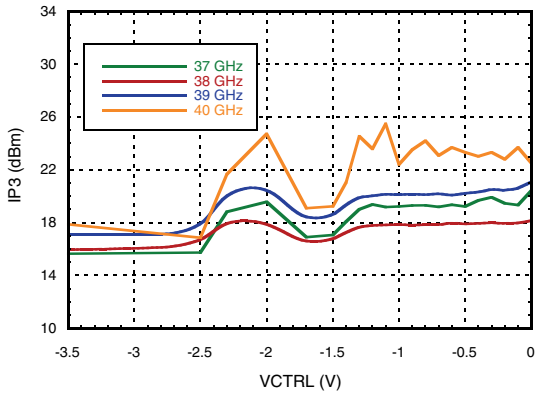


Conversion Gain, USB vs. Control Voltage

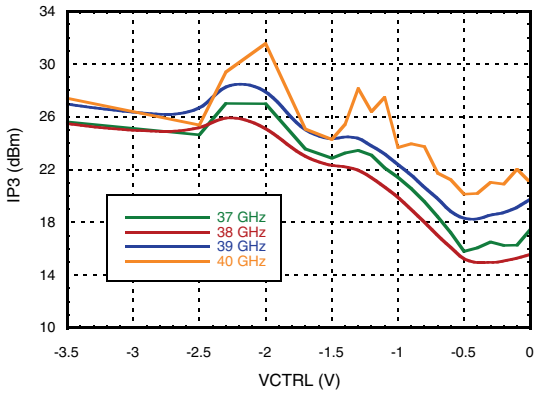


Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3000 MHz

Input IP3, USB vs. Control Voltage



Output IP3, USB vs. Control Voltage



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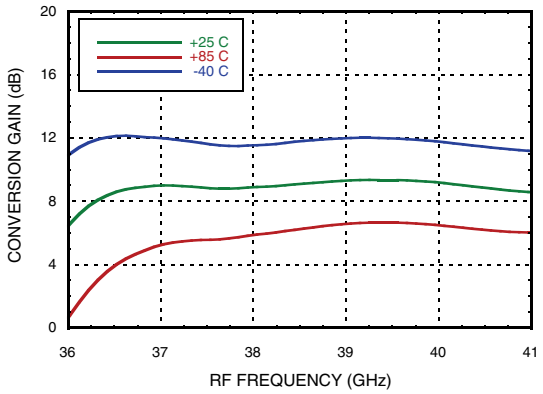
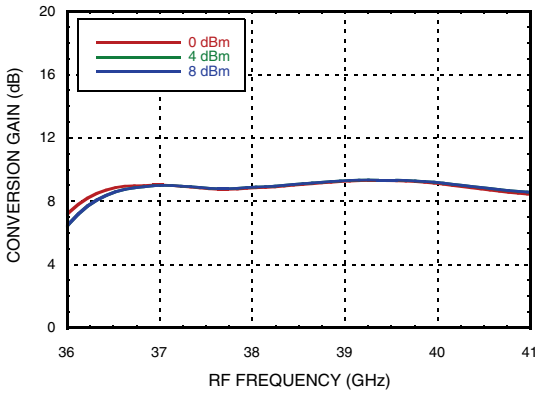
GaAs MMIC I/Q UPCONVERTER 37 - 40 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3750 MHz

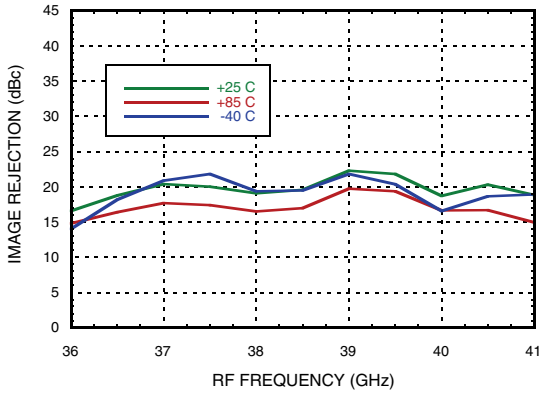
Conversion Gain, USB vs. Temperature



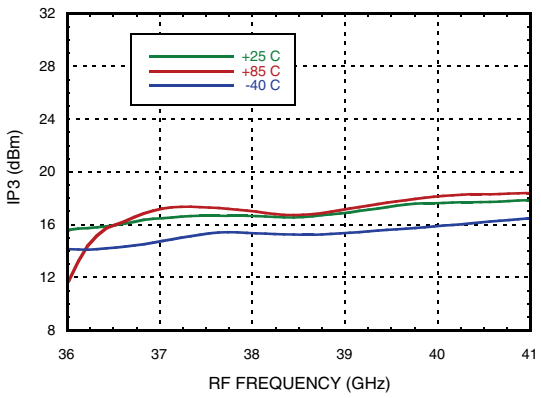
Conversion Gain, USB vs. LO Drive



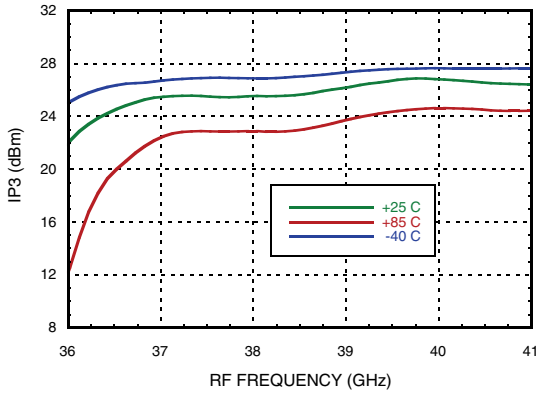
Sideband Rejection vs. Temperature



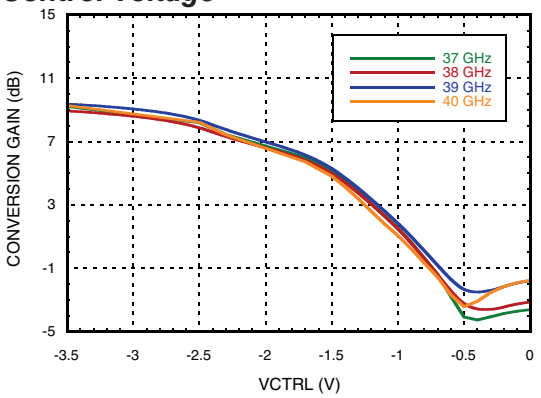
Input IP3, USB vs. Temperature



Output IP3, USB vs. Temperature

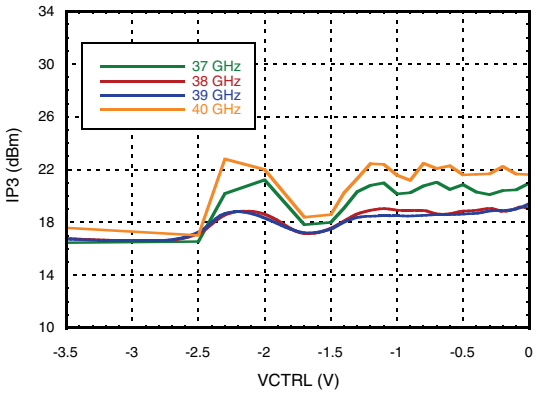


Conversion Gain, USB vs. Control Voltage

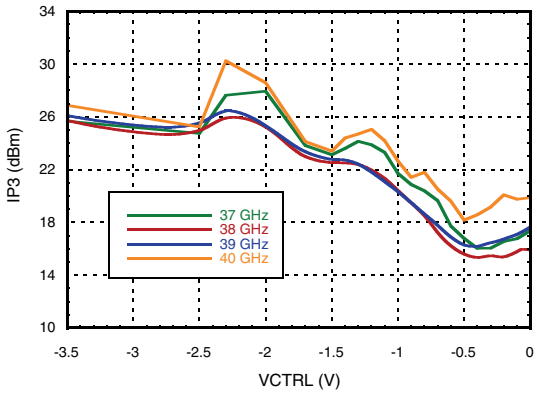


Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3750 MHz

Input IP3, LSB vs. Control Voltage



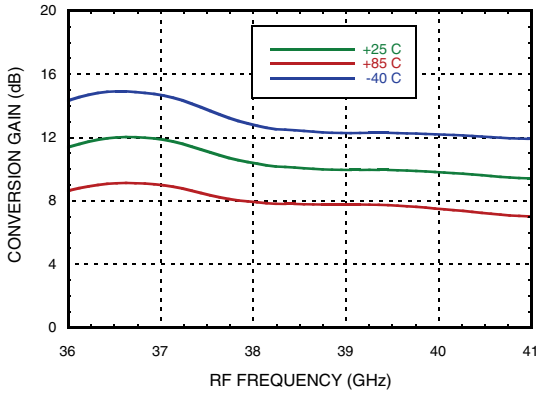
Output IP3, LSB vs. Control Voltage



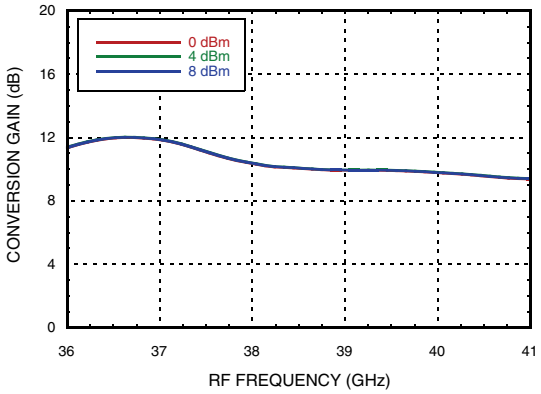
[1] Data taken without external IF 90° hybrid
[2] All values in dBc below RF power level (2LO + IF) USB

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 1000 MHz

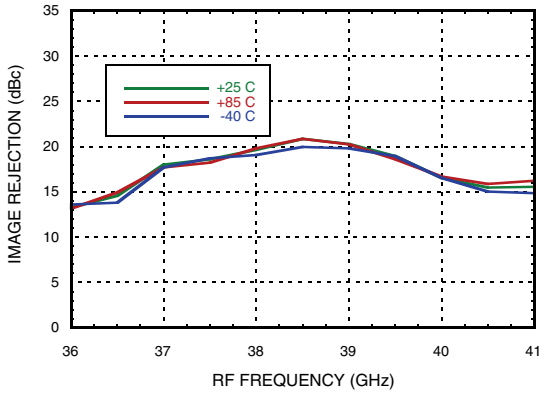
Conversion Gain, USB vs. Temperature



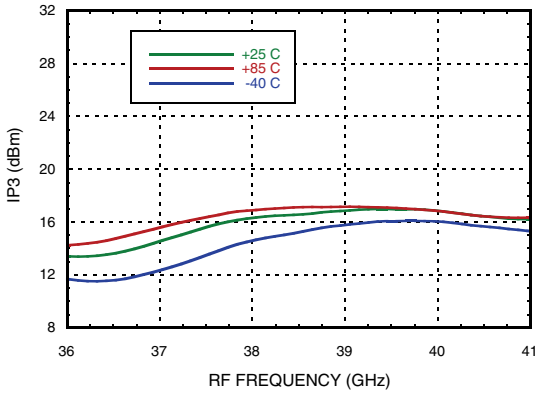
Conversion Gain, USB vs. LO Drive



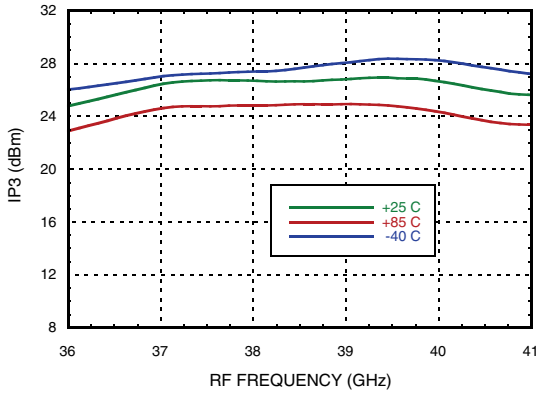
Sideband Rejection vs. Temperature



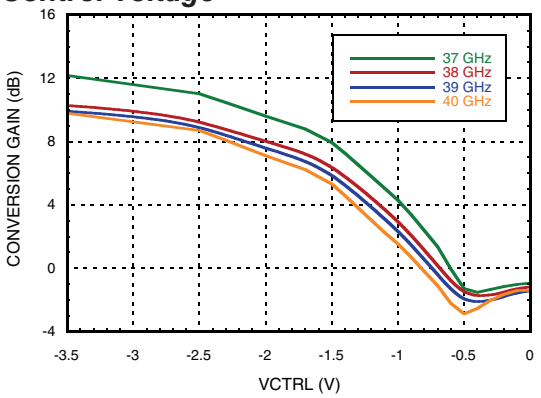
Input IP3, USB vs. Temperature



Output IP3, USB vs. Temperature

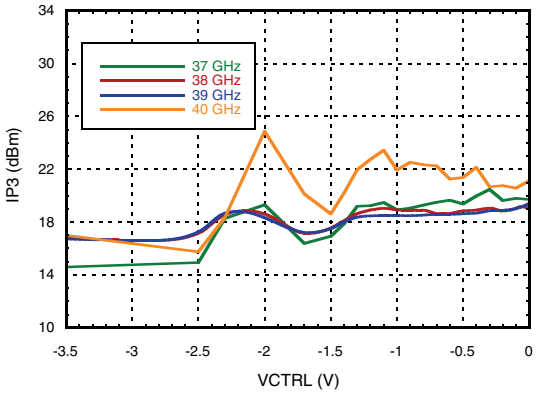


Conversion Gain, USB vs. Control Voltage

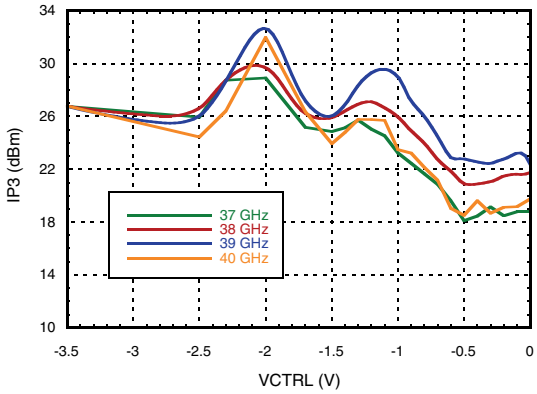


Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 1000 MHz

Input IP3, LSB vs. Control Voltage



Output IP3, LSB vs. Control Voltage



MxN Spurious Outputs [1][2]

	nLO				
mIF	0	1	2	3	4
0		31	4		
1	54	65	0		
2	62	71	40		
3	122	90	62		
4	122	122	122		
5	122	122	122		

IF = 2.35 GHz @ -8 dBm
LO = 17.575 GHz @ +4 dBm

MxN Spurious Outputs [1][2]

	nLO				
mIF	0	1	2	3	4
0		32	5		
1	56	59	0		
2	59	79	64		
3	118	118	68		
4	118	118	118		
5	118	118	118		

IF = 3 GHz @ -8 dBm
LO = 17.75 GHz @ +4 dBm

MxN Spurious Outputs [1][2]

	nLO				
mIF	0	1	2	3	4
0		31	5		
1	56	51	0		
2	61	70	48		
3	118	84	58		
4	122	122	122		
5	122	122	122		

IF = 4 GHz @ -8 dBm
LO = 17.75 GHz @ +4 dBm

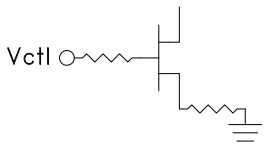
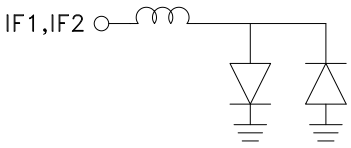
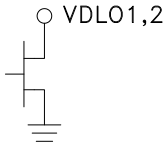
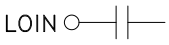
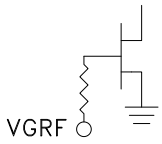
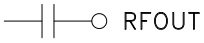
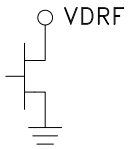
MxN Spurious Outputs [1][2]

	nLO				
mIF	0	1	2	3	4
0		34	4		
1	59	54	0		
2	71	72	39		
3	120	86	62		
4	120	122	120		
5	120	120	120		

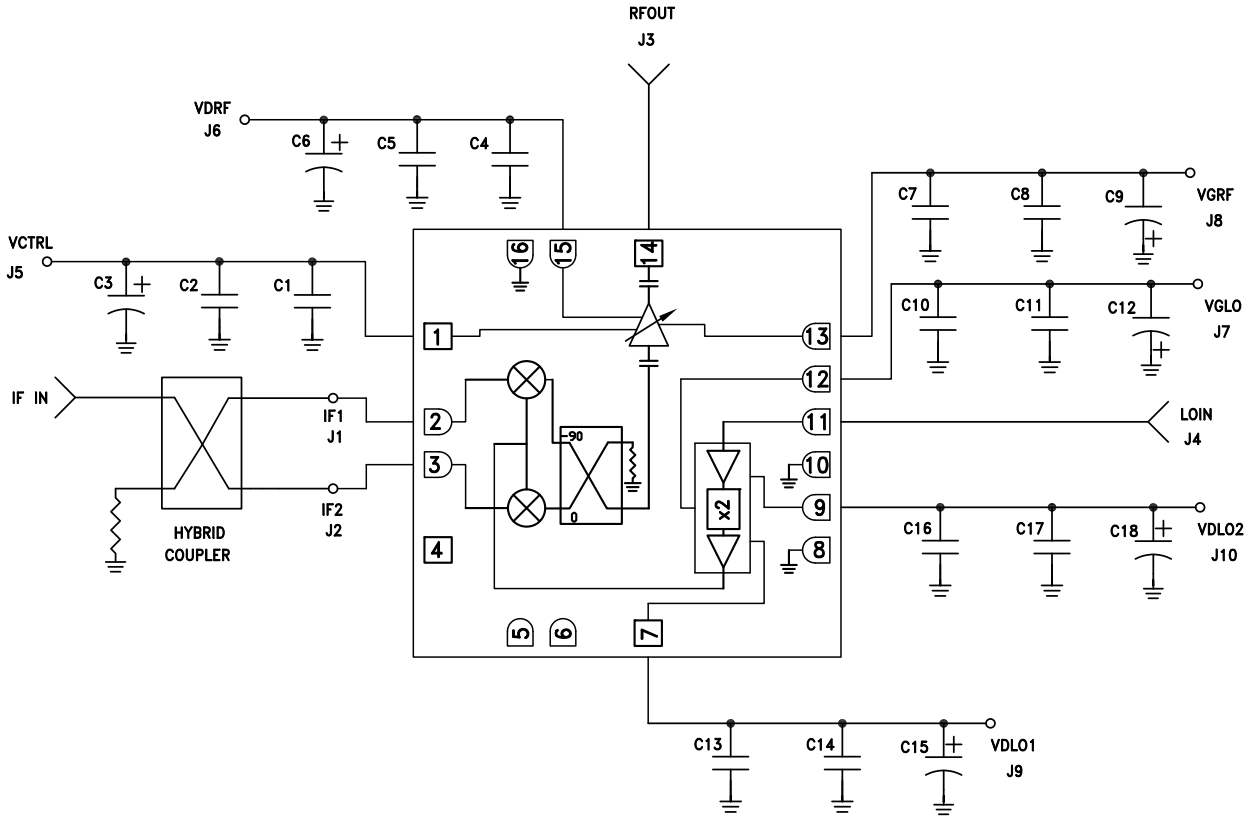
IF = 1 GHz @ -8 dBm
LO = 18.5 GHz @ +4 dBm

[1] Data taken without external IF 90° hybrid
[2] All values in dBc below RF power level (2LO + IF) USB

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	VCTRL	Vary Vctrl from -3.5V to 0V to adjust conversion gain.Maximum Gain occurs at -3.5V. Current draw << 1 mA.	
2	IF1	Pins are DC coupled Must not source or sink more than +/- 3 mA for applications requiring operation to DC.	
3	IF2		
4, 5, 6	N/C	No connection required. The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
7	VDLO1	Bias for multiplier input buffer amp. The recommended DC voltage is +3V.	
9	VDLO2	Bias for multiplier input buffer amp. The recommended DC voltage is +3V.	
8, 10, 16	GND	These pins and package bottom must be connected to RF/DC ground.	
11	LOIN	LO input port. The recommeded LO power is 0 to 8 dBm.	
12	VGLO	Adjust VGLO for -1V to 0V to set the multiplier quiescent current to 150 mA (200 - 230 mA with LO Drive).	
13	VGRF	Adjust VGRF for -1V to 0V to set the VGA current to 200 mA.	
14	RFOUT	RF output port.	
15	VDRF	Bias voltage for the VGA. The recommended DC voltage is +3V.	

Typical Application



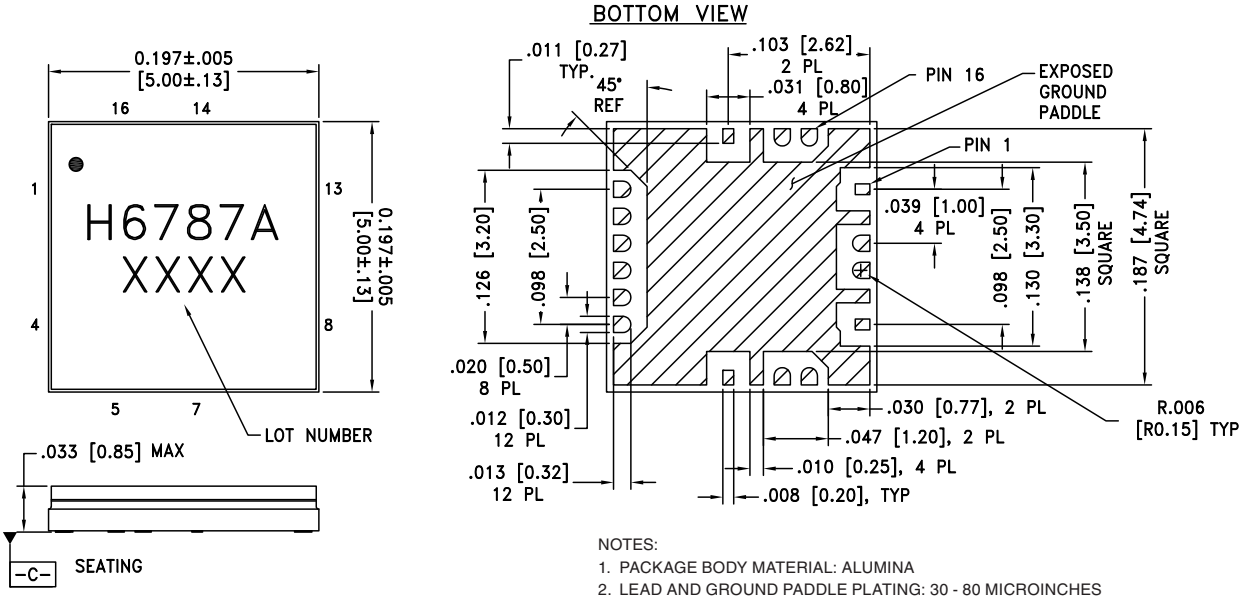
C1, C4, C7, C10, C13, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C8, C11, C14, C17	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C9, C12, C15, C18	4.7 µF Capacitor, Case A Pkg.

Absolute Maximum Ratings

IF Input	+20 dBm
LO Input	+10 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85°C) (derate 18.3 mW/°C above 85°C)	1.65 W
Thermal Resistance (channel to ground paddle)	54.6 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class1A

ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS

Outline Drawing



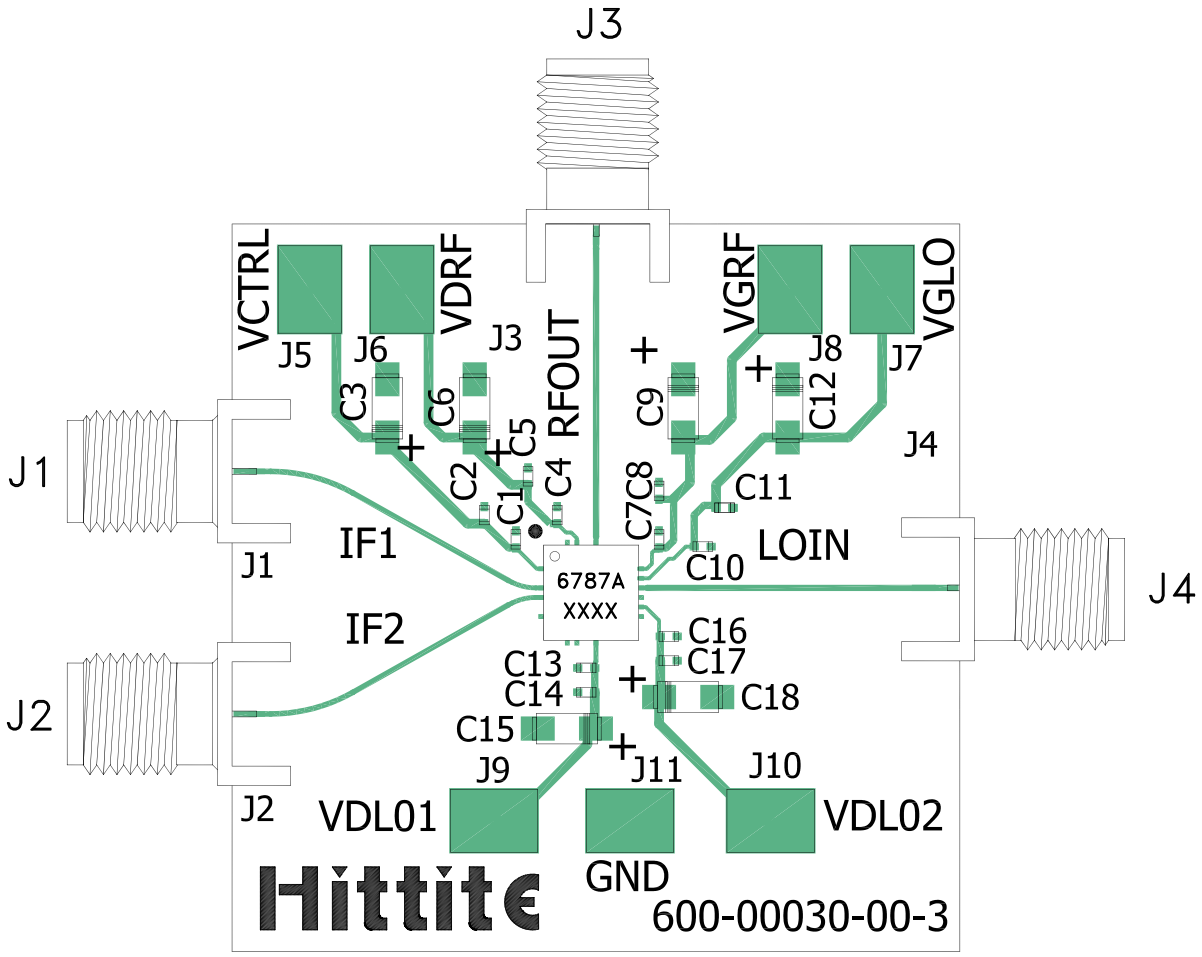
NOTES:
1. PACKAGE BODY MATERIAL: ALUMINA
2. LEAD AND GROUND PADDLE PLATING: 30 - 80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKLE
3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC6787ALC5A	Alumina, White	Gold over Nickel	MSL3 [1]	6768A XXXX

[1] Max peak reflow temperature of 260 °C
[2] 4-Digit lot number XXXX

Evaluation PCB



List of Materials for Evaluation PCB Eval01-HMC6787ALC5A [1]

Item	Description
J1, J2	SMA Connector
J3, J4	K-Connector SRI
J5 - J11	DC Pins
C1, C4, C7, C10, C13, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C8, C11, C14, C17	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C9, C12, C15, C18	4.7 µF Capacitor, Case A
U1	HMC6787ALC5A Upconverter
PCB [2]	600-00030-00 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

Notes: